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# Incorporating Rare-Earth Terbium(III) Ions into Cs<sub>2</sub>AgInCl<sub>6</sub>:Bi Nanocrystals toward Tunable Photoluminescence

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Abstract: The incorporation of impurity ions or doping is a promising method for controlling the electronic and optical properties and the structural stability of halide perovskite nanocrystals (NCs). Herein, we establish relationships between rare-earth ions doping and intrinsic emission of lead-free double perovskite Cs<sub>2</sub>AgInCl<sub>6</sub> NCs to impart and tune the optical performances in the visible light region.  $Tb^{3+}$  ions were incorporated into  $Cs_2AgInCl_6$  NCs and occupied  $In^{3+}$  sites as verified by both crystallographic analyses and first-principles calculations. Trace amounts of Bi doping endowed the characteristic emission ( ${}^{5}D_{4} \rightarrow {}^{7}F_{6-3}$ ) of  $Tb^{3+}$  ions with a new excitation peak at 368 nm rather than the single characteristic excitation at 290 nm of  $Tb^{3+}$ . By controlling  $Tb^{3+}$  ions concentration, the emission colors of Bi-doped Cs<sub>2</sub>Ag- $(In_{1-x}Tb_x)Cl_6$  NCs could be continuously tuned from green to orange, through the efficient energy-transfer channel from selftrapped excitons to  $Tb^{3+}$  ions. Our study provides the salient features of the material design of lead-free perovskite NCs and to expand their luminescence applications.

# Introduction

Lead-free halide perovskite nanocrystals (NCs) have attracted intense research efforts recently as possible alternatives to lead-halide perovskite NCs to address the ambient instability and lead toxicity issues of such compounds for the realization of industrial development.<sup>[1]</sup> Several classes of related materials that replace lead with other elements have been explored.<sup>[2]</sup> Isovalent substitution of Pb<sup>2+</sup> with less-toxic Sn<sup>2+</sup> or Ge<sup>2+</sup> is a straightforward method. Unfortunately, the resulting compounds CsBX<sub>3</sub> (B = Sn<sup>2+</sup> and Ge<sup>2+</sup>) exhibit poorer stabilities than lead-halide perovskites ascribed to the easy oxidations of Sn<sup>2+</sup> and Ge<sup>2+</sup> to their corresponding 4 + states.<sup>[3]</sup> Another important alternative approach to replacing two Pb<sup>2+</sup> ions with one monovalent (M') and one trivalent (M'') cation to form the M' and M'' octahedra, obtaining a A<sub>2</sub>M'M''X<sub>6</sub> three dimensional (3D) double perovskite structure. Theoretically, in the generic chemical formula A<sub>2</sub>M'M''X<sub>6</sub>, M' could be Ag<sup>+</sup>, Na<sup>+</sup>, Cu<sup>+</sup> and M'' could be Bi<sup>3+</sup>, Sb<sup>3+</sup>, In<sup>3+</sup> to form many possible compositions.<sup>[4]</sup> Experimentally, Cs<sub>2</sub>AgBiX<sub>6</sub>, Cs<sub>2</sub>AgInCl<sub>6</sub>, Cs<sub>2</sub>AgSbCl<sub>6</sub>, Cs<sub>2</sub>NaBiCl<sub>6</sub> and their alloys have been synthesized as colloidal NCs.<sup>[5]</sup> However, most air-stable double perovskite NCs have either large band gaps or forbidden optical transitions,<sup>[6]</sup> leaving the challenges in realizing optoelectronic applications and thus motivating researchers to develop strategies to improve the optoelectronic properties.<sup>[7]</sup>

Lanthanide (rare earth) ion incorporation or doping is considered a promising approach to imparting and tailoring the optical and optoelectronic performances of inorganic materials over the visible and near infrared region. The lanthanide ions (Ln<sup>3+</sup>) usually exhibit unique emissions with sharp spectral linewidths compared with transition metal ions whose emissions are relatively broadband. Ln<sup>3+</sup> ions prefer locating in sites with a coordination environment  $CN \ge 6$ (CN = coordination number). Lead-free double perovskites and lead halide perovskites provide octahedral coordination (CN = 6) for the B-site cation and M<sup>"</sup>-site cation, respectively, thus making them ideal hosts for lanthanide-ion incorporation.<sup>[8]</sup> For lead-halide perovskite NCs, different lanthanide ions have been successfully doped into the lattice for imparting optical functionality or improving the stability of NCs.<sup>[9]</sup> However, to our knowledge, only several successful examples of Ln<sup>3+</sup> ions doping into the lead-free perovskite

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NCs were reported so far, mostly in the near infrared region. For example,  $Yb^{3+}$  or  $Er^{3+}$  ions doping into  $Cs_2AgInCl_6$  NCs was explored by Kim's and Nag's group;<sup>[10]</sup> Chen et al. doped  $Yb^{3+}$  and  $Mn^{2+}$  ions into  $Cs_2AgBiX_6$  NCs;<sup>[11]</sup> Tang's group doped Ho<sup>3+</sup> ions into  $Cs_2AgNaInCl_6$  NCs;<sup>[12]</sup> Song et al. reported  $Eu^{3+}$ -doped  $Cs_3Bi_2Br_9$  quantum dots for  $Cu^{2+}$  detection.<sup>[13]</sup> Inspired by the studies described above, it is valuable to unveil new  $Ln^{3+}$  ions doping effects on lead-free double perovskite NCs and impart the optical properties in the visible range.

Herein, we incorporated Tb<sup>3+</sup> ions into lead-free double perovskite Cs<sub>2</sub>AgInCl<sub>6</sub> NCs, simultaneously preserving the consistent crystal structure and uniform cubic morphology, to impart and tune the photoluminescence (PL) performances. Accordingly, the Tb<sup>3+</sup> ions site occupation was verified from experimental analyses and first-principles calculations. More importantly, Bi<sup>3+</sup> ions doping in Cs<sub>2</sub>AgInCl<sub>6</sub> NCs adjusted the excitation of Tb<sup>3+</sup> ions emission to 368 nm and variation of Tb<sup>3+</sup> ions doping concentration achieved tunable emission colors from green to orange. Moreover, we explored the emission mechanism and further proposed the efficient energy transfer channel with 368 nm excitation from selftrapped excitons (STEs) to Tb<sup>3+</sup> ions in Bi doped Cs<sub>2</sub>Ag- $(In_{1-r}Tb_r)Cl_6$  NCs. Our study provides insights to dope  $Ln^{3+}$ ions into the lead-free double perovskite NCs to generate multiple emissions and to expand their potential as optoelectronic materials.

### **Results and Discussion**

All samples were synthesized via a high temperature hot injection method as reported in our previous work.<sup>[14]</sup> To clarify whether the rare earth Tb<sup>3+</sup> ion is doped into the Cs<sub>2</sub>AgInCl<sub>6</sub>:Bi, XRD patterns of the as-prepared Bi doped  $Cs_2Ag(In_{1-x}Tb_x)Cl_6$  NCs with different  $Tb^{3+}$  concentrations x of 0, 8.3%, 14.9%, 17.1% were firstly analyzed as shown in Figure 1. All the NCs possessed the same cubic phase with no impurity detected and slight shifts of the diffraction peak of (022) plane toward smaller angle were observed for the doped samples (Figure 1a). The amounts of Tb<sup>3+</sup> ions and In<sup>3+</sup> ions included in the nanocrystals were ascertained by the inductively coupled plasma (ICP) measurement (Table S1 and S2 in the Supporting Information), which provided an approximately 2% Bi/In ratio. Figure 1 b,c show Rietveld refinement of the XRD patterns of Cs<sub>2</sub>AgInCl<sub>6</sub>:Bi and  $Cs_2Ag(In_{82.9\%}Tb_{17.1\%})Cl_6:Bi$  (corresponding to Tb/In = 0.206) nanocrystals. All the peaks were indexed by cubic cell (Fm3m)with parameters close to the bulk Cs<sub>2</sub>Ag(In<sub>82.9%</sub>Tb<sub>17.1%</sub>)Cl<sub>6</sub>.<sup>[15]</sup> Therefore, this structure was taken as the starting model for Rietveld refinement performed using TOPAS 4.2. Refinements were stable and gave low R-factors (Table S3, Figure 1 b,c). Coordinates of atoms and main bond lengths were present in Table S4 and Table S5, respectively. Corresponding to the peak shift in Figure 1a, the cell volume V(x) increased with Tb<sup>3+</sup> ions doping concentrations x as shown in Figure 1 d. Considering that the ionic radii  $r(Tb^{3+}, CN = 6) = 0.923$  Å is smaller than  $r(Cs^+, CN =$ 12) = 1.88 Å and  $r(\text{Ag}^+, \text{CN} = 6) = 1.15 \text{ Å}$ ,  $\text{Tb}^{3+}$  ions should



**Figure 1.** a) XRD patterns of Bi doped  $Cs_2Ag(In_{1-x}Tb_x)Cl_6$  (x=0, 8.3%, 14.9%, 17.1%) (left) and magnified XRD patterns in the approximate range of 20–25° (right). b),c) Rietveld refinement of XRD patterns for  $Cs_2AgInCl_6$ :Bi and  $Tb^{3+}$ -doped  $Cs_2AgInCl_6$ :Bi with Tb/In=0 and 0.206, respectively. d) Variation of cell volume as a function of the value of Tb/In. Insets show the schematic of corresponding crystal structure with  $Tb^{3+}$  ions doping. e)  $k^2$ -weighted Tb  $L_3$ -edge EXAFS spectrum and f) corresponding Fourier transform of  $Cs_2Ag(In_{82.9\%}Tb_{17.1\%})Cl_6$ :Bi NCs fitting as a function of *R*.

not locate in Cs and Ag sites. Only the ionic radii  $r(In^{3+}, CN = 6) = 0.8$  Å is smaller than that of Tb<sup>3+</sup> ions, which verifies that the partial Tb<sup>3+</sup> ions are incorporated into the lattice of Cs<sub>2</sub>AgInCl<sub>6</sub> NCs and substitute partial In<sup>3+</sup> ions.

To further clarify the occupied crystallographic sites of Tb<sup>3+</sup> ions in the Cs<sub>2</sub>AgInCl<sub>6</sub> lattice, Tb L<sub>3</sub>-edge EXAFS measurement and analysis for the Cs2Ag(In82.9%Tb17.1%)Cl6:Bi NCs were conducted and demonstrated in Figure 1e, f. The EXAFS data obtained was processed in Athena (version 0.9.25) for background, pre-edge line and post-edge line calibrations. Then corresponding Fourier transform (FT) fitting was carried out in Artemis (version 0.9.25). The k<sup>2</sup> weighting, k-range of 3–12 Å<sup>-1</sup> and R range of 1–3 Å were used for the fitting. The model of  $Tb^{3+}$  ions at  $In^{3+}$  sites in Cs<sub>2</sub>AgInCl<sub>6</sub> was used to calculate the simulated scattering paths. The four parameters: coordination number (CN), bond length (R), Debye-Waller factor ( $\sigma^2$ ) and E<sub>0</sub> shift ( $\Delta E_0$ ) were fitted without fixed, constrained, or correlated. It can be seen that in Figure 1e,f the spectra were fitted well, with CN = 5.6 ± 0.4,  $\Delta E_0 = 4.6 \pm 0.6 \text{ eV}$ ,  $\sigma^2 = 0.0051 \pm 0.0006 \text{ Å}^2$ , and R factor = 0.003, and the details are presented in Table S6. Besides, the fitted bond distance R is  $2.65 \pm 0.01$  Å from Table S6. In the structure of Cs<sub>2</sub>AgTbCl<sub>6</sub>, the bond length of Tb-Cl is 2.66 Å. While in the structure of  $Cs_2AgInCl_6$ , the bond lengths of In-Cl, Ag-Cl, and Cs-Cl are 2.56, 2.72, **Research Articles** 

3.74 Å, respectively. Thus the fitted bond length *R* in the  $Cs_2Ag(In_{82.9\%}Tb_{17.1\%})Cl_6$ :Bi NCs is closest to the bond length of Tb–Cl. In the FT, the relative decrease in the peak position compared with the actual interatomic distance could be attributed to the photoelectron phase shift.<sup>[16]</sup> In conclusion, all these results support that the doped Tb<sup>3+</sup> ions occupied In<sup>3+</sup> sites.

XPS analyses were also performed to confirm the presence of Tb in the Cs<sub>2</sub>Ag(In<sub>82.9%</sub>Tb<sub>17.1%</sub>)Cl<sub>6</sub>:Bi NCs (Figure S1). The survey XPS spectrum (Figure S1a) showed that both undoped and Tb<sup>3+</sup> ions doped NCs contained Cs, Ag, In, Cl elements, however, only small amount of Tb can be found in Tb<sup>3+</sup>-doped NCs. Figure S1b exhibited the two peaks of Tb 3d signals at 1242 and 1277 eV in the 17.1 mol % Tb<sup>3+</sup>-doped sample readily proving the existence of Tb<sup>3+</sup> ions in the Cs<sub>2</sub>AgInCl<sub>6</sub>:Bi NCs. Furthermore, comparing the high resolution XPS spectra of In 3d and Ag 3d for Tb<sup>3+</sup>-doped and undoped NCs (Figure S1c,d), a slight shift to higher binding energy for  $\mathrm{In}^{3+}\, 3d_{_{3/2}}$  and  $\mathrm{In}^{3+}\, 3d_{_{5/2}}$  but little variations for Ag<sup>3+</sup> 3d appeared. The slight shift could be attributed to the lattice expansion after the successful incorporation of Tb<sup>3+</sup> ions, further confirming the conclusion above that Tb<sup>3+</sup> ions occupy In<sup>3+</sup> sites rather than Ag<sup>+</sup> sites.<sup>[9e]</sup> TEM images shown in Figure 2a,c,e,g demonstrated the microstructure of asprepared undoped and Tb<sup>3+</sup>-doped Cs<sub>2</sub>AgInCl<sub>6</sub>:Bi NCs. It can be seen that the NCs have similar cubic morphology with the high crystallinity and uniformity. "Dark dots" attached on the NCs could be Ag<sup>0</sup> NCs that have been discussed in previous studies.<sup>[5c, 14]</sup> The selected area electron diffraction (SAED) patterns of corresponding NCs shown in Figure 2b,d,f,h revealed the presence of (022) and (004) planes of cubic phase, confirming the formation of the consistent perovskite structure. Moreover, as presented in insets of Figure 2a,c,e,g, the lattice constants increased from 0.37 to 0.39 nm with the increase in Tb<sup>3+</sup> ions doping concentration, further verifying the lattice expansion consistent with the XRD results above.

Next, we performed first-principles calculations for simulating the difficulty in defect formation and the stabilities of the defect systems of  $Tb^{3+}$  ions incorporated into  $Cs_2AgInCl_6$ lattice. Figure 3 a showed the relaxed structures of six possible dopant conditions (named A to F) of  $Tb^{3+}$ -doped  $Cs_2AgInCl_6$ , where A–C represented interstitial doping of Tb located previously between nearest Cs–Cs, Cs–Ag and Cs–In atoms, while D–F represented substitution doping of Tb at Cs, Ag,



Figure 2. a),c),e),g) TEM and HR-TEM images of Bi doped Cs<sub>2</sub>Ag-(ln<sub>1-x</sub>Tb<sub>x</sub>)Cl<sub>6</sub> (x = 0, 8.3 %, 17.1 %, 20.1 %) NCs, respectively. b),d),f),h) Corresponding SAED patterns of Tb<sup>3+</sup> ions doped Cs<sub>2</sub>AgInCl<sub>6</sub>:Bi NCs.



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**Figure 3.** a) Relaxed structures of possible doping conditions of  $Cs_2AgInCl_6$  with  $Tb^{3+}$  dopant; b) Formation energies for different doping conditions. Condition A–C: interstitial doping of Tb located previously between nearest Cs–Cs, Cs–Ag, and Cs–In atoms, respectively; condition D–F: substitution doping of Tb at Cs, Ag, and In site, respectively.

and In site, respectively. The interstitial formation energies (for A–C) were calculated by [Eq. (1)]:

$$E_{\text{for}} = E_{\text{tot}}(\text{Cs}_2\text{AgInCl}_6 + \text{Tb}) - E_{\text{tot}}(\text{Cs}_2\text{AgInCl}_6) - \mu_{\text{Tb}}$$
(1)

For substitution situations, the substitution formation energies (for D–F) were calculated by [Eq. (2)]:

$$E_{\text{for}} = E_{\text{tot}}(\text{Cs}_2\text{AgInCl}_6 + \text{Tb}) - E_{\text{tot}}(\text{Cs}_2\text{AgInCl}_6) + \mu_{\text{X}} - \mu_{\text{Tb}}$$
(2)

where  $E_{tot}(Cs_2AgInCl_6 + Tb)$  and  $E_{tot}(Cs_2AgInCl_6)$  represent the total energy of Tb-doped  $Cs_2AgInCl_6$  system and undoped  $Cs_2AgInCl_6$  crystal, respectively.  $\mu_X$  (X = Cs, Ag. or In) and  $\mu_{Tb}$  is the chemical potential of the substitution atom (Cs, Ag. or In) and Tb atom calculated as the corresponding crystal energy per atom. All the formation energies for different dopant conditions are graphically represented in Figure 3b. Condition A–C have negative formation energies, but with obvious localized twist near the Tb dopant (especially in Condition B), which is mainly caused by the small localized atomic distance between the dopant and the nearest atoms. Condition D (Cs–Tb substitution) has positive formation energies compared with other doping conditions with negative formation energies, indicating an inappropriate solubility of substitution doping of Tb in Cs–Tb substitution. For

#### 11636 www.angewandte.org

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other substitution doping conditions, the formation energies are lower than those of interstitial doping conditions, and In– Tb substitution (Condition F) has the lowest  $E_{\rm for}$  of -4.77 eV, indicating that Ag–Tb and In–Tb substituted environments are more favorable, and Tb substitution at In site was expected to be more easily realized and more feasibly synthesized than Ag site and other interstitial doping in experiments. Besides, the doping of Tb<sup>3+</sup> ions at In<sup>3+</sup> ions site could be more favorable as an isoelectronic doping rather than other charged doping site or interstitial doping. In combination of the EXAFS, XPS analyses and the ionic radii comparisons discussed previously, the substitution of Tb atoms at In<sup>3+</sup> site could be the main occupation for Tb<sup>3+</sup> ions involved Cs<sub>2</sub>AgInCl<sub>6</sub>.

Bismuth dopant influence on the In-based halide perovskites represented by Cs<sub>2</sub>AgInCl<sub>6</sub> has been intensely investigated in the previous study.<sup>[5b, 17]</sup> For relative light doping, the dopant system exhibit band gap manipulability<sup>[5b]</sup> and absorption edge shift. The energy shift is mainly caused by the Bi 6p orbital mixed in the conduction band minimum (CBM) orbital state.<sup>[7b]</sup> The formation energy for the Bi-Tb binary doping system could be increased due to the relaxation of internal stress comparing with that of Tb doping. But in our study, the Bi contents for samples with different Tb content (up to ca. 20%) are basically consistent (ca. 2%), indicating that the Bi influence on the formation energy and CBM for different samples could be limited and consistent. Therefore, we consider  $Cs_2AgIn_{1-r}Bi_rCl_6$  as an established system for the further Tb<sup>3+</sup> doping, and we focus on the Tb effect on the structural and electronic properties. Thus, we fixed the influence of Bi by neglecting the small amount of Bi in Cs2AgInCl6, and investigate the Tb influence on the Cs<sub>2</sub>AgIn<sub>1-x</sub>Bi<sub>x</sub>Cl<sub>6</sub> system. The dopant structures with different Tb<sup>3+</sup> ions doping concentrations were established and fully relaxed with details introduced in the computational method section. For the dopant Cs<sub>2</sub>AgInCl<sub>6</sub>, the Bi dopants remain the lattice vectors and similar geometric structure of pristine Cs<sub>2</sub>AgInCl<sub>6</sub>, and the calculated structural volume increased 0.77% and 1.62% for Tb<sup>3+</sup> ions doping concentration of 12.5% and 25%, respectively (see Figure S2a), which is in consistent with the variation tendency of experimental measurement. The formation energies for these two dopant structures are 0.77 and 1.81 meV/atom (see Figure S2b), respectively. Such relative formation energies indicate a probability on the formation at room temperature. The calculated absorption coefficients for Cs<sub>2</sub>AgInCl<sub>6</sub> with different doping concentrations were shown in Figure S3a, as the band edge showed obvious blue shift as the Tb<sup>3+</sup> ions doping concentration increased, causing enhancement of the optical band gap. Such band gap expansion could also be confirmed in the calculated total density of state (TDOS) shown in Figure S3b, where the CBM moved towards higher energy level when Tb<sup>3+</sup> ions concentration increased. This could be contributed to the Tb involvement in the Cs<sub>2</sub>AgInCl<sub>6</sub>. The Tb<sup>3+</sup>-doped Cs<sub>2</sub>AgInCl<sub>6</sub> could be understood as a solid solution  $Cs_2AgIn_{1-x}Tb_xCl_6$  which could be decomposes to two stable double perovskite: Cs<sub>2</sub>AgInCl<sub>6</sub> and Cs<sub>2</sub>AgTbCl<sub>6</sub> (both  $Fm\bar{3}m$ ). As the Perdew-Burke-Ernzerhof (PBE) band gap of Cs<sub>2</sub>AgTbCl<sub>6</sub> (3.63 eV) is larger than that of Cs<sub>2</sub>AgInCl<sub>6</sub>

(1.03 eV), the band gap for the  $Tb^{3+}$  ions incorporated Cs<sub>2</sub>AgInCl<sub>6</sub> could be inevitably enlarged when the Tb<sup>3+</sup> ions concentration increased. Such band gap variation has already been observed in solid solution perovskite systems with both cation<sup>[7b]</sup> and anion<sup>[18]</sup> transmutation. The partial density of state (PDOS) for undoped, 12.5% Tb<sup>3+</sup>-doped and 25% Tb<sup>3+</sup>-doped Cs<sub>2</sub>AgInCl<sub>6</sub> are represented in Figure S3c–e. For Tb<sup>3+</sup>-doped Cs<sub>2</sub>AgInCl<sub>6</sub>, the upper valence band and valence band maximum (VBM) are mainly contributed by Cl 3p and Ag 3d orbitals analogous to Cs<sub>2</sub>AgInCl<sub>6</sub>, while the CBM state is mainly contributed by In 5s with a small amount of Tb 6s state mixed in. For different Tb<sup>3+</sup> ions concentrations, the Tb 6s state around CBM increased dramatically when Tb<sup>3+</sup> ions doping concentration increased. Due to the larger band gap of Cs<sub>2</sub>AgTbCl<sub>6</sub> comparing with that of Cs<sub>2</sub>AgInCl<sub>6</sub>, such increase of Tb 6s state at CBM would make an enhanced contribution of Tb, causing CBM shift to higher energy level, and eventually increase in band gap.

Having looked deep into the alloving nature of double perovskite NCs, we investigated the luminescence features. 368 nm, Bi<sup>3+</sup>-undoped Under the excitation of  $Cs_2Ag(In_{82.9\,\%}Tb_{17.1\,\%})Cl_6~NCs$  showed blue emission at 470 nm instead of STEs emission and Bi3+-doped  $Cs_2Ag(In_{82.9\,\%}Tb_{17.1\,\%})Cl_6$  NCs showed broadband STEs emission at 580 nm, as reported before.<sup>[14]</sup> We also conduct the fs-TA spectroscopy for Bi<sup>3+</sup>-doped Cs<sub>2</sub>AgInCl<sub>6</sub> NCs to verify that the broadband orange emission originates from STEs. A broad photoinduced absorption upon excitation at 365 nm was observed as the direct character of self-trapped excitons (Figure S4).<sup>[19]</sup> As a comparison, as shown in Figure 4a,  $Cs_2Ag(In_{82.9\,\%}Tb_{17.1\,\%})Cl_6$  without  $Bi^{3+}$  ions exhibited no STEs emission and no characteristic luminescence of Tb<sup>3+</sup> ions. The optical band gap of Cs2Ag(In82.9%Tb17.1%)Cl6 NCs was calculated to be about 4.39 eV from the absorption spectra and corresponding Tauc plot (Figure S5), larger than the corresponding energy from 368 nm illumination. Besides, the absorption spectra of Cs<sub>2</sub>AgInCl<sub>6</sub> and Cs<sub>2</sub>AgInCl<sub>6</sub>:Bi NCs and the emission of Cs<sub>2</sub>AgInCl<sub>6</sub> NCs at 290 nm excitation are shown in Figure S6. Although Cs<sub>2</sub>AgInCl<sub>6</sub> NCs exhibited a broad emission at 290 nm excitation, we could not see the intrinsic emission of Cs<sub>2</sub>AgInCl<sub>6</sub> NCs in Figure 4 a because the low photoluminescence quantum yield of Cs2AgInCl6 NCs (ca.  $\hat{1}$ %).<sup>[5a]</sup> The sharp contrast in the PL intensity between Tb<sup>3+</sup> ions and Cs<sub>2</sub>AgInCl<sub>6</sub> NCs at 290 nm excitation made the characteristic emission of Tb<sup>3+</sup> ions more likely to be excited by its intrinsic excitation band at about 290 nm rather than an energy transfer process. However, after doping a small amount of Bi<sup>3+</sup> ions, Cs<sub>2</sub>Ag(In<sub>82.9%</sub>Tb<sub>17.1%</sub>)Cl<sub>6</sub> exhibited both broad emission derived from STEs and sharp emission peaks located at around 490 nm, 550 nm and 620 nm, corresponding to the intrinsic transition of  $Tb^{3+}$  ions  ${}^{5}D_{4}$ - ${}^{7}F_{6}$ ,  ${}^{5}D_{4}$ - ${}^{7}F_{5}$  and  ${}^{5}D_{4}$ - $^{7}F_{3}$ , respectively with the 368 nm excitation (Figure 4b). The excitation wavelength adjustment also endows the material with the wide range application. Indirectly, the phenomenon suggested that the Tb<sup>3+</sup> ions emission in Bi doped Cs<sub>2</sub>Ag- $(In_{1-x}Tb_x)Cl_6$  NCs was not excited directly by 368 nm but excited via an energy transfer channel from the Bi doped  $Cs_2Ag(In_{1-x}Tb_x)Cl_6$  NC host to  $Tb^{3+}$  ions. Moreover, the emission intensity excited by 368 nm was higher than that by **Research Articles** 



*Figure 4.* a),b) Emission spectra (right side of spectra, excited by 368 nm and 290 nm) and excitation spectra (left side of spectra, monitored at 550 nm) of undoped and Bi-doped  $Cs_2Ag(In_{82.9\%}Tb_{17.1\%})Cl_6$ . Insets show an expansion and photographs of the corresponding sample under 254 nm and 365 nm UV irradiation. c) PLE (left side of spectrum, monitored at 550 nm) and PL spectra (right side of spectrum, excited by 368 nm) of Bi doped  $Cs_2Ag(In_{1-x}Tb_x)Cl_6$  (x=0, 1.5%, 3.9%, 8.3%, 17.1%, 20.1% NCs. Insets: the photos of the corresponding nanocrystals solution in hexane under the UV-light (365 nm) excitation. d) PL decay curves of STEs emission from corresponding samples monitored at 368 nm excitation and 520 nm emission. e) PL decay dynamics of Tb<sup>3+</sup> ions emission (550 nm) from Tb<sup>3+</sup>-doped  $Cs_2AgInCl_6$ :Bi NCs with different doping contents monitored at 368 nm excitation. f) Energy-level diagram of Tb<sup>3+</sup> ions doped  $Cs_2AgInCl_6$ :Bi NCs and the proposed luminescence mechanism.

290 nm (Figure 4b), related to more efficient emission of  $Tb^{3+}$  ions through the energy transfer channel than directly via intrinsic excitation band, and the mechanism will be addressed below.

To shed more light on the doping concentration effect on luminescence properties of Cs2AgInCl6:Bi NCs, the controlled experiment for the samples with different amount of Tb<sup>3+</sup> ions alloyed was conducted. As presented in Figure 4c and Figure S7, excited at 368 nm (the characteristic excitation of STEs in Cs<sub>2</sub>AgInCl<sub>6</sub>:Bi), the relative intensity of Tb<sup>3+</sup> ions emission located at 550 nm increased gradually with incremental  $\mathrm{Tb}^{3+}$  ions added and then decreased from 17.1 mol % Tb<sup>3+</sup> ions alloyed caused by concentration quenching, which could be the direct existence of the energy transfer in the Bi doped  $Cs_2Ag(In_{1-x}Tb_x)Cl_6$  NCs from STEs to  $Tb^{3+}$  ions. Surprisingly, the STEs emission in highly Tb<sup>3+</sup>-doped Cs<sub>2</sub>AgInCl<sub>6</sub>:Bi system almost disappeared and only the strong and sharp lines of Tb<sup>3+</sup> ions emission existed, indicating that high doping concentration promoted the energy transfer from STEs to  $Tb^{3+}$  ions. Simultaneously, as a result of energy transfer, the concentration dependence of  $\mathrm{Tb}^{\mathrm{3+}}$  ions could further tune the emission colors of Bi doped Cs2Ag- $(In_{1-x}Tb_x)Cl_6$  NCs from green to orange as shown in insets of Figure 4c. The absolute photoluminescence quantum yields were 10.1%, 8.1%, 8.0%, 9.2% and 6.6%, respectively, corresponding to the  $\text{Tb}^{3+}$  concentrations of 0, 3.9, 8.3, 17.1, 20.1 mol%. In addition, to further prove the existence of energy transfer channel, the photoluminescence decay curves for STEs emissions at different Tb<sup>3+</sup> ions concentrations were measured and exhibited in Figure 4d. The monitored emission wavelength was 520 nm to avoid the interference of Tb<sup>3+</sup> ions characteristic emission. The photoluminescence decay curves were fitted by triexponential functions with shorterlived components ( $\tau_1$ ,  $\tau_2 < 500$  ns) possibly from deep surface trapping processes<sup>[20]</sup> and a longer-lived component ( $\tau_3 >$ 500 ns) corresponding to the STEs lifetime (Table S7). The average lifetime ( $\tau_{ave}$ ) can be calculated with [Eq. (3)],<sup>[9f]</sup>

$$\tau_{\rm ave} = \sum_{i} A_i \tau_i \tag{3}$$

The values of average lifetimes ( $\tau_{ave}$ ) were calculated to be 1371.9, 1327.9, 1274.4, 993.7, 577.9, 319.5 ns corresponding to x = 0, 1.5, 3.9, 8.3, 17.1, 20.1 mol %, respectively. Thus, the lifetime for STEs decreased with the concentration of Tb<sup>3+</sup> ions increased (Table S7), further indicating that the improved energy transfer from STEs to Tb<sup>3+</sup> ions promoted the decay of STEs. The energy transfer efficiency  $\eta_{\rm T}$  from STEs to Tb<sup>3+</sup> ions can be obtained by from [Eq. (4)],<sup>[21]</sup>

$$\eta_{\rm T} = 1 - \tau_x / \tau_0 \tag{4}$$

where  $\tau_x$  and  $\tau_0$  are the lifetimes of STEs in the presence and absence of Tb<sup>3+</sup> ions. The values of  $\eta_T$  were estimated to be

3.2%, 7.1%, 27.6%, 57.9% and 76.7% for x = 1.5, 3.9, 8.3, 17.1, 20.1 mol%, respectively, revealing that the energy transfer was efficient and the efficiency  $(\eta_T)$  increased with increase in Tb<sup>3+</sup> ions concentration (Table S7). Besides, the PL decay curves of Bi doped  $Cs_2Ag(In_{1-x}Tb_x)Cl_6$  monitored at 550 nm were shown in Figure 4e. The values of  $Tb^{3+}$  ions average lifetimes ( $\tau_{ave}$ ) were determined to be 8.9, 8.8, 8.7, 7.6, 7.4 ns at x = 1.5, 3.9, 8.3, 17.1, 20.1 mol%, respectively (Table S8). It is obvious that the lifetime of the  $Tb^{3+}$  ions decreases gradually as increase in Tb<sup>3+</sup> ions content which can be ascribed to the concentration quenching effect. Based on the results discussed above, a possible photoluminescence mechanism for Bi doped  $Cs_2Ag(In_{1-x}Tb_x)Cl_6$  is proposed and shown in Figure 4 f. Under the excitation at 368 nm, the electrons are excited from the ground states into the excited states of Cs<sub>2</sub>AgInCl<sub>6</sub>:Bi NC host and then shift to the selftrapped state through the nonradiative relaxation, emitting broad orange light due to the STEs recombination.<sup>[1c,14]</sup> Simultaneously, partial energy is transferred to  $Tb^{3+}$  ion. Subsequently, electrons at higher level of Tb<sup>3+</sup> ions are relaxed to the lowest excited level <sup>5</sup>D<sub>4</sub>, and then go back to the ground state, causing the Tb<sup>3+</sup> ions ( ${}^{5}D_{4} \rightarrow {}^{7}F_{6-3}$ ) characteristic emission. And thus, the emission colors of Bi doped Cs<sub>2</sub>Ag- $(In_{1-x}Tb_x)Cl_6$  NCs could be continuously tuned from green to orange.

# Conclusion

In conclusion, we report the first example of  $Tb^{3+}$  ions incorporated Cs<sub>2</sub>AgInCl<sub>6</sub>:Bi NCs to impart and tune the photoluminescence. The structural analysis and the lowest formation energy of -4.77 eV for substitution doping of Tb<sup>3+</sup> at the In<sup>3+</sup> site from first-principles calculation demonstrate that Tb<sup>3+</sup> ions occupy In<sup>3+</sup> sites in Cs<sub>2</sub>AgInCl<sub>6</sub> NC hosts. Noted that Bi doping in Cs<sub>2</sub>AgInCl<sub>6</sub> NCs adjust the excitation of Tb<sup>3+</sup> ions and allow Tb<sup>3+</sup> ions to exhibit a characteristic emission under 368 nm excitation, endowing the material with the potential light-emitting diode application under the excitation of commercial near ultraviolet chips. In addition, the introduction of Tb<sup>3+</sup> ions brought tunable emission from green to orange and we have proposed the energy transfer channel with 368 nm excitation from STEs to Tb<sup>3+</sup> ions in Bi doped  $Cs_2Ag(In_{1-x}Tb_x)Cl_6$  NCs. This work establishes the relationship between the intrinsic emission from lead-free perovskite NCs and the luminescence resulting from lanthanide-ion doping and further promotes the development of new lead-free perovskite NCs for emerging optoelectronic application.

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# **Conflict of interest**

The authors declare no conflict of interest.

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